

1st/2nd generation Laser-Produced Plasma source system for HVM EUV lithography

- Hakaru Mizoguchi*1, Tamotsu Abe, Yukio Watanabe, Takanobu Ishihara, Takeshi Ohta,Tsukasa Hori, Tatsuya Yanagida, Hitoshi Nagano, Takayuki Yabu, Shinji Nagai, Georg Soumagne, Akihiko Kurosu, Krzysztof M. Nowak, Takashi Suganuma, Masato Moriya, Kouji Kakizaki, Akira Sumitani, Hidenobu Kameda*1, Hiroaki Nakarai*1, Junichi fujimoto
- *1 Gigaphoton Ltd. :400 Yokokura shinden,Oyama, Tochigi,Japan Komatsu Ltd. : 3-25-1 Shinomiya, Hiratsuka, Japan

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Outline

1. Introduction

2. Engineering Test source

- 1st Generation (ETS) device: System experiment
 - Operation Data

• 10Hz device: Critical issue experiment

- Vaporization experiment
- Ionization experiment
- Magnetic mitigation
- Pre-pulse and high CE

3. HVM EUV light source

- Product roadmap
- 2nd Generation device: Development status
 - Configuration
 - Latest status
- 4. Summary







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EUV sources キャピラリー 集光ミラー Plasma guiding Sn supply Magnet 真空容器。 High power パルス pulsed CO., laser 電源 -Plasma LPP: CO₂ laser and Sn source æ EUV 放電 ✓ High power pulsed CO₂ laser CO2 laser Magnetic field plasma mitigation \checkmark 放電 ラズマ ✓ Pre-Pulse plasma technology 中間集光点:IF **EUV Collector** デブリシールド So-collector 真空ポンプ

| Туре | LPP | | DPP |
|--------------------|--|---------------------------------|--|
| Maker | Gigaphoton | Company A | Company B |
| Size | Large | Very Large | Small |
| Power (at present) | 104W/21W | 90W/20W | 34W/34W |
| Plasma | No electrode | No electrode | Disc electrode |
| Mitigation | Pre pulse + Magnet | Gas | Gas+mechanical shutter |
| Life limitation | (several 1000 hr) | Several 10 hr | Several 10 hr |
| Bottle neck | - | Mirror | Electrode/Mirror |
| Remark | Theoretically no limit Engineering works still to be done | Trade off of power and lifetime | Trade off of power and lifetime Trade off of power and beam quality |

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ETS system configuration



System layout





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System operation Data (ETS device)

| | SPIE 2010 (Feb.2010) | EUV Symposium (Oct.2010) | Latest Data (Feb,2011) |
|-----------------------------|-------------------------|-----------------------------|---------------------------|
| EUV power (@ I/F) | 69 W | 104 W | 42 W |
| EUV power (clean @ I/F) | 33 W | 50 W | 20 W |
| Duty cycle | 20 % | 20 % | 5% |
| Max. non stop op. time | >1 hr | <1 hr | >7 hr |
| Average CE | 2.3 % | 2.5 % | 2.1% |
| Dose stability :simulation | (+/- 0.15%) | | - |
| Droplet diameter | 60 μ m | 60 μ m | 30 μm |
| CO ₂ laser power | 5.6 kW | 7.9 kW | 3.6kW |



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Droplet generator lifetime improvement (\phi30 \mum)

> Operation time improved from <1 hour to >7 hours





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System operation result on ETS

>Long time system operation demonstrated

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 > Operation duration:
 > Droplet
 > Full repetition rate:
 > In burst clean power:
 20W (average) 25W (max)



Conclusion of ETS device experiment

"ETS experiment clarified 3 key challenges are essential"



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Collector mirror protect Concept

All Sn atoms should be ionized.

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- 1 Magnet field is effective for guiding ions not to going to mirror
- **②** All Sn fragments and atoms are needed to be ionized



Critical issue investigation with 10Hz device

- Double pulse optimization
- Debris mitigation mechanism
- Higher CE investigation





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Setup configurations

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Droplet transformation by pre-pulse

Smaller fragments Spread homogeneously







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Droplet shooting scheme

Proper pre-pulse condition

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Laser induced fluorescence (LIF) imaging for tin atom

Advantages

- Spectrally selective pumping and observation
- High sensitivity
- Cross sectional imaging with a sheet laser beam



Grotrian diagram for tin atom



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Principle of LIF

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Atom measurement by LIF - 2

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Remaining atoms was estimated by subtracting w/ CO2 vs w/o CO2 measurement



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Conclusion of 10Hz device experiment

"Even with smaller than $20\mu m$ droplet,

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Ce=3.3% and perfect vaporization is simultaneously achieved"





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EUV product roadmap



★ 1st source delivery > GL200E will be delivered to scanner manufacture at Mid Y2011.
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Clean power roadmap



| EUV model | | ETS | GL200E | GL200E+ | GL400E |
|---------------------------|----|-------|--------|---------|--------|
| Drive laser power | kW | 10 | 23 | 33 | 40 |
| Conversion efficiency | % | 3.0 | 5.0 | 5.0 | 6.0 |
| C1 mirror collector angle | sr | 5.5 | 5.5 | 5.5 | 5.5 |
| efficiency* | % | 74 | 74 | 74 | 74 |
| C1 mirror reflectivity | % | (50) | 57 | 57 | 57 |
| Optical transmission | % | 95 | 95 | 95 | 95 |
| SPF (IR, DUV) | % | N/A** | 62 | 62 | 62 |
| Total EUV power (after SF | W | 100 | 250 | 350 | 500 |



* Against hemisphere (Calculation base) ** w/o SPF



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GL200E proto constructed at Hiratsuka facility



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Main Amplifier performance

> Main amplifier characteristics : experimental results

- ✓ ~10kW output achieved at 3kW input power
- ✓ Good beam quality: M²<2.0

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Pointing stability of CO2 laser w/ control, duty cycle 30%

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Beam profile



| Operation conditions | |
|----------------------|--------|
| Rep. rate [kHz] | 100 |
| Duty [%] | 30 |
| ON pls [pulse] | 30,000 |
| OFF time [msec] | 700 |
| Testing time [min] | 120 |



Pointing stability of Pre-Pulse laser

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w/ control, duty cycle 30%





Beam profile



| Operation conditions | |
|----------------------|--------|
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Droplet Generator for GL200E

Video

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 $20 \,\mu$ m, 10kHz



Slow image @nozzle



Position stability at 10 kHz



| ltem | unit | target | result |
|----------------------|------|--------|--------|
| position stability x | um | +/-20 | 7 |
| position stability z | um | +/-20 | 18 |

- > Position stability is within specification for proto.
- > Droplet generator on proto is working within spec.



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Scalability toward to 250W clean power

- 3.3% CE realized by 20 μm droplet

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- It indicates ~100W clean power if operated at 100kHz*





KO

Research and development scenery











Presentation on 02 March @SPIE 2011 1



κομητίς

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We delayed 3 months. Now recovering !

Real first EUV light ... High power and debris free light will come within a few weeks !





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Summary

1st generation integrated setup LPP source (ETS) and 10 Hz device:

- One order smaller fragment (droplet size reduction from 60µm to 30 µm) extends operation time to 7 hours under 20W(clean power @I/F, 5%duty) level operation.
- 10Hz experiment proved debris mitigation concept experimentally. That is; proper pre-inonization and main ionization make >93% ionization. This technology enables clean light source with combination with magnetic field.
- 10Hz experiment clarify CE (Conversion Efficiency) improvement, with <20µm droplet we found the region where Ce >3.3% and perfect vaporization are simultaneously possible.

2st generation LPP source (GL200E):

- Concept of design and outline is reported.
- We already finished assembling and final engineering of components. The first light will be realized within a few weeks.







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